



[Maxim](#) > [Design Support](#) > [Technical Documents](#) > [Application Notes](#) > [Amplifier and Comparator Circuits](#) > APP 3983  
[Maxim](#) > [Design Support](#) > [Technical Documents](#) > [Application Notes](#) > [Power-Supply Circuits](#) > APP 3983

Keywords: resonant- reset, forward converter, single-transistor, sinusoidal reset, synchronous-rectifier

#### APPLICATION NOTE 3983

# Designing Single-Switch, Resonant-Reset, Forward Converters

By: Suresh Hariharan, Director and Product Definer  
Mar 20, 2007

*Abstract: Among power-converter topologies, the single-transistor, forward converter is one of the most common for power levels below 100 watts. This article describes an improvement to that circuit called the "single-transistor, resonant-reset, forward converter," which eliminates the reset winding and a diode ( $D_{TR}$ ). Several other advantages of this design will be discussed.*

A similar article appeared in the October 2005 issue of *Power Electronics Technology*.

## Introduction

Single-transistor, resonant-reset forward converters are commonly used in DC-DC converter modules for power levels below 100 watts. These devices are also quite useful for DC-DC converters with widely adjustable output voltages. This article, however, describes an improved circuit called the "single-transistor resonant-reset forward converter." This design eliminates the reset winding and a diode ( $D_{TR}$ ), and offers several distinct advantages.

The duty cycle for this resonant-reset converter can exceed 50%, making it suitable for low-cost DC-DC converters that operate from wide input voltages and deliver widely varying outputs. The absence of a reset winding reduces costs by simplifying the transformer, especially for the planar transformers widely used in high-density DC-DC converter modules. Finally, the resonant-reset circuit's sinusoidal reset voltage reduces EMI.

## Conventional Single-Switch Forward Converter Design

To properly appreciate the resonant-reset topology, we must first understand the conventional single-switch forward converter (**Figure 1a**). When switch Q1 turns on, the transformer current rises from zero and the diode,  $D_{TR}$ , is reverse biased. Transformer magnetizing current builds up to a value  $I_M = V_{IN}T_{ON}/L_M$ , where  $T_{ON}$  is the ON time per switching cycle and  $L_M$  is the magnetizing current.

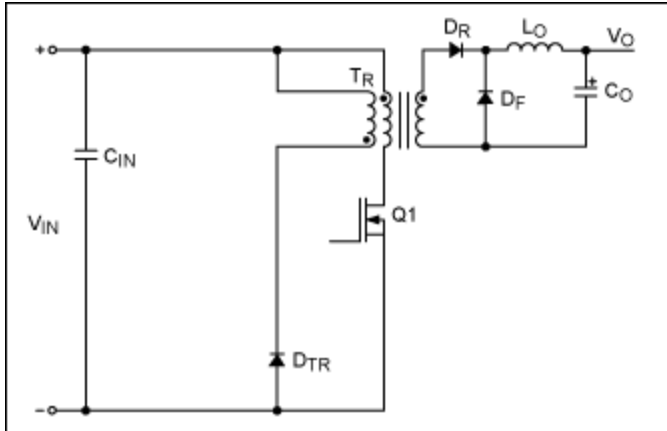


Figure 1a. Conventional single-transistor forward converter.

During the switch ON period, the load current,  $I_O$ , is reflected in the primary as  $I_p = I_O N_S / N_P$ , where  $N_S$  is the number of secondary turns and  $N_P$  is the number of primary turns. Output voltage is  $V_O = V_{IN} D N_S / N_P$ , where  $D = T_{ON} / T_S$  and  $1/T_S$  is the switching frequency. Magnetizing current in the transformer primary just before turn-off is  $V_{IN} T_{ON} / L_M$ . When Q1 turns off, the transformer voltage tends to reverse. Voltage on the  $D_{TR}$  cathode keeps increasing until  $D_{TR}$  turns on.

For typical applications the  $N_P / N_R$  turns ratio is 1, where  $N_R$  is the number of turns in the primary reset winding. The transformer magnetizing current now decreases from  $I_M$  to zero. When it reaches zero, the transformer is fully reset and voltage across the transformer remains at zero until the next switching cycle starts. The maximum duty cycle,  $D_{MAX}$ , in these applications is limited to 50%.

## Resonant-Reset Forward Converter Design

Single-switch resonant-reset forward converters are characterized by the absence of a reset winding (Figure 1b). During the OFF time, the transformer resets (without loss) through a resonant circuit that consists of: the magnetizing inductance; and the combined capacitance of the switch, primary winding, and all reflected secondary capacitances including the rectifying-diode capacitance.

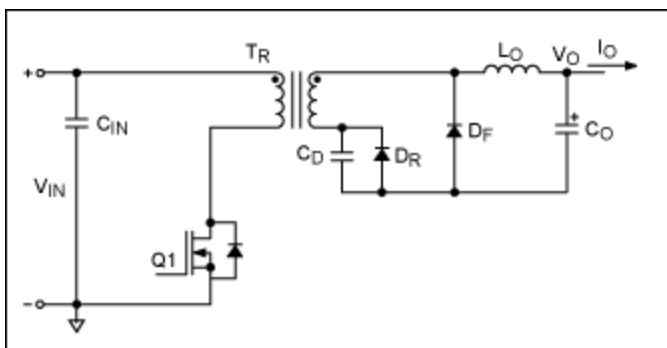


Figure 1b. Single-switch, resonant-reset forward converter.

## Description of Operation

The following assumptions are made for this circuit analysis:

- The circuit has reached steady-state operation.
- $L_O$  and  $C_O$  (fairly large) can be considered infinite.

- Leakage inductance is neglected.
- Drops due to the diode and switch on-resistance are neglected.

Steady-state operation for the circuit comprises three intervals in each switching cycle:

### Interval 1

Initially,  $t = 0$  and Q1 is ON (**Figure 2a**). The transformer is magnetized with a ramp current during the switch ON period. Secondary current flows through the secondary diode,  $D_R$ , and the voltage across capacitance,  $C_D$ , is approximately zero.  $C_D$  includes the internal diode capacitance and the external capacitance added across  $D_R$ . The primary magnetizing current has a value  $I_1$  at the start of this interval, and  $I_2$  at the end of the interval.

$$I_2 = I_1 + \frac{V_{IN} \times T_{ON}}{L_M} \quad (\text{Eq. 1})$$

Primary current is the sum of the reflected current,  $I_O(N_S/N_P)$ , and the primary magnetizing current.

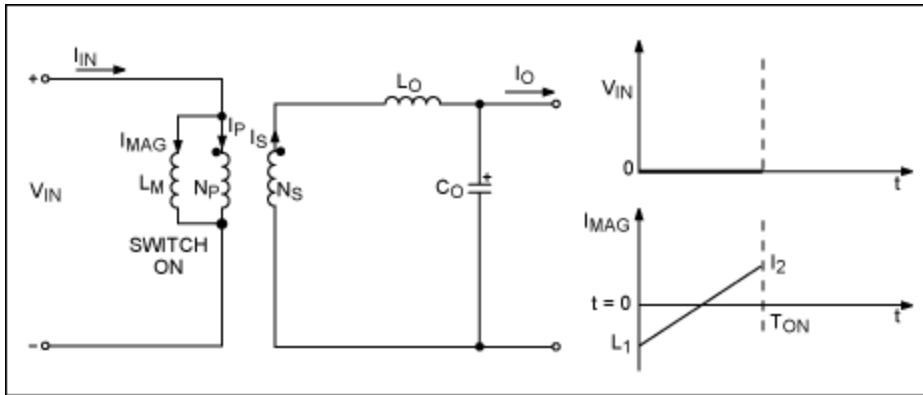


Figure 2a. From Figure 1b, an equivalent circuit for the voltage on Q1 and the primary magnetizing-current waveform during Interval 1 (not to scale).

### Interval 2

When the switch is turned off, the switch drain-to-source voltage begins to rise (**Figure 2b**). When that voltage exceeds  $V_{IN}$ , the secondary diode,  $D_R$ , turns off and the freewheeling diode,  $D_F$ , turns on. A sinusoidal demagnetization current starts to flow through the resonant circuit that is formed by the parallel combination of transformer magnetizing inductance,  $L_M$ , and the capacitance,  $C_R$ , reflected across the transformer primary. That capacitance,  $C_R$ , is the sum of all capacitances across the primary, including the reflected diode capacitance,  $C_D$ :

$$C_R = C_D \left( \frac{N_S}{N_P} \right)^2 + C_S + C_T \quad (\text{Eq. 2})$$

where  $C_S$  is the primary switch capacitance and  $C_T$  is the transformer primary capacitance.  $C_D$  is the external capacitance across diode  $C_D$  (diode capacitances  $\ll C_D$ ). Interval 2 ends at the end of  $T_{ON} + T_R$ , where  $T_R$  is one half of a resonant interval.

$$f_{RES} = \frac{1}{2\pi\sqrt{L_M \times C_R}} \quad (\text{Eq. 3})$$

$$T_R = \pi\sqrt{L_M \times C_R} \quad (\text{Eq. 4})$$

The external capacitance,  $C_R$ , charges from zero to a peak value of  $I_2\sqrt{L_M/C_R}$  during this interval, and then discharges back to zero. The magnetizing current,  $I_1$ , at the end of the interval should therefore equal  $-I_2$ . Voltage on the primary switch at the end of this interval is  $V_{IN}$ , but voltage on the switch reaches a peak of  $V_{IN} + I_2\sqrt{L_M/C_R}$  halfway through the interval.

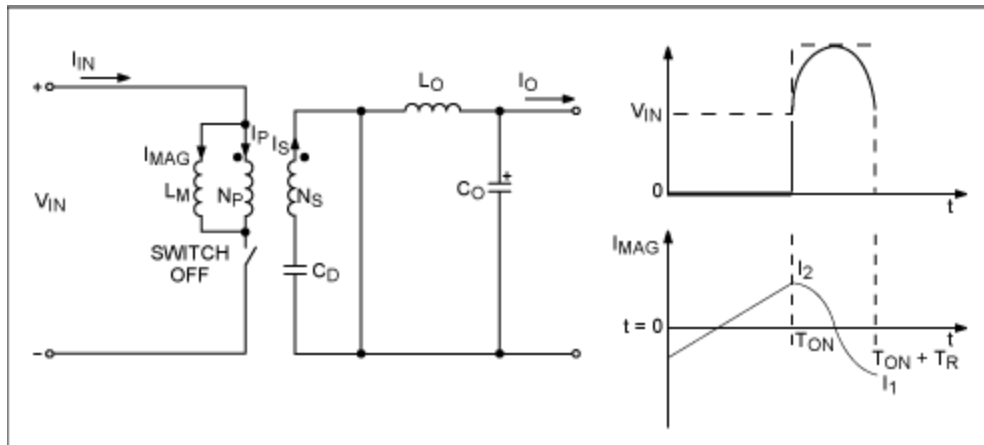


Figure 2b. From Figure 1b, an equivalent circuit for the voltage on Q1 and the primary magnetizing-current waveform during Interval 2 (not to scale).

### Interval 3

During this interval the diodes  $D_R$  and  $D_F$  are both ON; the primary switch is OFF (**Figure 2c**). Voltage across the transformer is zero, and the magnetizing current at the end of the interval equals  $-I_2$ . This ends a switching cycle. Because the circuit is at steady state, the current  $I_1$  therefore equals  $-I_2$ . Substituting for  $I_1$  in equation 1, we see that the primary magnetizing current at the start of each switching cycle is:

$$I_1 = -\frac{(V_{IN} \times T_{ON})}{2L_M} \quad (\text{Eq. 5})$$

The primary-switch voltage remains at  $V_{IN}$  during Interval 3. Note at the end of  $T_S$ , that  $I_2 \neq I_1$  is possible if  $\pi\sqrt{L_M \times C_R} > (T_S - T_{ON})$ . In that case a full half-cycle of resonance has not been completed before the next switching cycle begins. Therefore the voltage across the primary switch exceeds  $V_{IN}$  at the start of each switching cycle. That condition increases the switching loss.

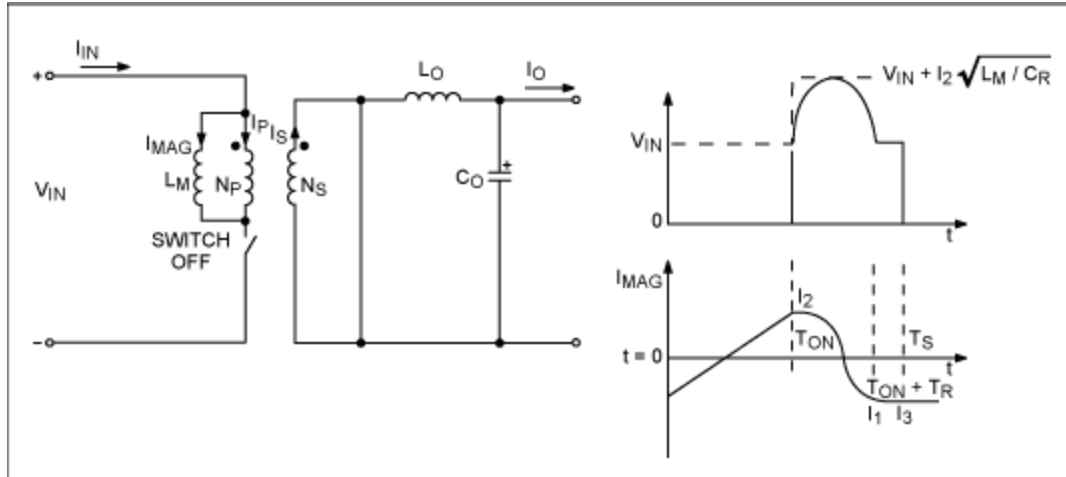


Figure 2c. From Figure 1b, an equivalent circuit for the voltage on Q1 and the primary magnetizing-current waveform during Interval 3 (not to scale).

## Transient Operation

Transient stresses on the primary switch and secondary output diodes can vary greatly, depending on the type of controller used in the application. If the design is not optimal, transients can cause failure in the primary switches or the secondary diodes.

Consider operation with a current-mode PWM controller. Initially, the power supply operates at no load and high line voltage. A load transient is applied (minimum load to full load), which causes an immediate duty-cycle step to maximum duty cycle. In turn, that event causes a large increase in the transformer's magnetizing current, and may saturate the transformer unless its design accounted for such transients. The resonant-reset voltage is much higher than that during steady-state operation, and can cause failure in the forward diode or the primary switch.

To combat this problem, we introduce a volt-microsec clamp. Consider the controller above with a maximum-duty-cycle clamp that is inversely proportional to the input voltage. That arrangement limits the maximum flux excursion along the transformer's BH loop during a transient, which in turn allows the use of a smaller transformer. Transient-voltage stress on the forward diode and the primary switch is significantly less, but is still higher than during steady-state operation.

Now consider the operation of this converter type with a very light load, and using diodes for rectification. Magnetizing current is very close to zero during this mode of operation, and the duty cycle is low. If we now apply a load transient (from no load to full load), the duty cycle immediately increases to the maximum value allowed by the adaptive duty-cycle clamp. Before application of the transient, the magnetizing current is zero. The transient peak duty cycle at high line voltage is  $\frac{V_{INMIN} \times D_{max}(TR)}{V_{INMAX}}$ , where  $V_{INMIN}$  is the low-line input voltage,  $D_{MAX}(TR)$  is the maximum duty cycle at low line voltage set by the adaptive duty-cycle clamp, and  $V_{INMAX}$  is the input voltage at high line voltage. When a transient occurs, the magnetizing current increases from 0 to  $\frac{V_{INMIN} \times D_{max}(TR)}{L_M \times f_S}$  in the first switch ON cycle after the transient. Here  $L_M$  is the primary magnetizing inductance and  $f_{SW}$  is the switching frequency. After the switch turns off, the magnetizing current reverses in a sinusoidal fashion set by the magnetizing inductance,  $L_M$ , and capacitance,  $C_R$ . Peak voltage on the switch is:

$$V_{P_{MAX}(TR)} = V_{IN_{MAX}} + \frac{V_{IN_{MIN}} \times D_{max}(TR)}{L_M \times f_S} \times \sqrt{\frac{L_M}{C_R}} \quad (\text{Eq. 6})$$

For steady-state operation at full load and high line voltage, the peak steady-state voltage on the switch is:

$$V_{P_{MAX}(S)} = V_{IN_{MAX}} + \frac{V_{IN_{MIN}} \times D_{max}(S)}{2L_M \times f_S} \times \sqrt{\frac{L_M}{C_R}} \quad (\text{Eq. 7})$$

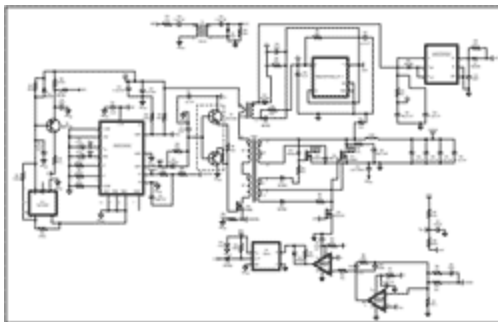
where  $D_{MAX}(S)$  is the steady-state duty cycle at full load and low line. In practical applications we try to set  $D_{MAX}(TR)$  slightly higher than  $D_{MAX}(S)$ . We also see that the peak transient reverse voltage on the diode  $D_F$  is more than twice as high as the peak steady-state reverse voltage with this type of PWM controller. For PWM controllers without the volt-microsec clamp, the transient voltage can be even higher.

If the circuit includes synchronous rectifiers, the inductor current does not become discontinuous and the magnetizing currents at light load and at full load are almost the same. For PWM current-mode controllers with volt-microsec clamps, the transient-voltage stress on the primary switch and the secondary diode,  $D_F$ , is closer to the peak steady-state voltage stress.

The behavior of voltage-mode controllers is similar to that of current-mode PWM controllers. Again, the use of an adaptive volt-microsec clamp can reduce stress. These converter types often include a duty-cycle soft-start that ramps up the duty cycle, thus controlling any buildup of magnetizing energy while alleviating voltage stress.

## Design Example

The working power supply of **Figure 3** accepts DC input voltages in the range 36V to 56V, and produces a 4V to 18V isolated variable output voltage, controlled by an adjustable external reference. The maximum output current is 0.4A and the switching frequency,  $f_{SW}$ , is 500kHz.



[More detailed image](#) (PDF, 212.38kB).

*Figure 3. Resonant-reset forward converter with an input range of ground to -48V<sub>OUT</sub> (36V to 56V) and output range 4V to 18V.*

The resonant-reset forward converter is most suitable for this design because it lets us maximize the duty cycle. That capability is necessary if the output voltage is to be properly controlled from high levels down to 4V. Otherwise, the PWM controller's minimum ON time is a limitation that can introduce problems. Synchronous rectifiers should be included to maximize efficiency and enable the PWM

controller to control the output voltage down to 4V at light loads. The current-mode PWM controller shown also includes an adaptive volt-microsec clamp.

### Adaptive Duty-Cycle Clamp

Because the power supply must turn on and provide full power at 36V, we set its turn-on point at 34.2V. That turn-on voltage includes a 5% margin to compensate for component tolerances. We then set the maximum duty cycle that corresponds to the turn-on point (set by the adaptive duty cycle) at 75%. That approach leaves 25% of the switching time available for resetting the transformer at the converter's lowest operating voltage.

### Primary MOSFET Voltage Rating

At the lowest operating voltage, the maximum available reset time for the transformer is:

$$T_R = \frac{(1 - D_{max})}{f_S} \quad (\text{Eq. 8})$$

where  $D_{MAX} = 0.75$  and  $f_{SW} = 5 \times 10^5$ . These values yield a reset time of  $0.5\mu s$ . To minimize switching loss, the magnetizing current should complete one half-cycle of sinusoidal "resonant ringing" as given by Equation 4. Therefore,  $\pi\sqrt{L_M \times C_R} = 0.5 \times 10^{-6}$ , and the peak steady-state voltage stress on the primary switch (obtained by substituting values in equation 7) is 208.6V. Thus, for this design we choose a switch rated at 250V.

### Transformer Design

Primary-to-secondary turns ratio for the transformer is n:

$$n \leq \frac{V_{INMIN} \times D_{max}}{V_{OUT}} \quad (\text{Eq. 9})$$

We choose a transformer with an EFD15 core of 3F3 material, and obtain  $n \leq 1.35$  by substituting values in Equation 9. The actual primary turns (30) and secondary turns (24) yield a turns ratio of 1.25. The magnetizing inductance for this transformer, wound using ungapped cores, is  $702\mu H \pm 25\%$ . Tolerance in the magnetizing inductance could produce a tolerance of  $+11\%/-13.4\%$  in the transformer's self-resonant frequency, not accounting for tolerance in the total capacitance appearing across the primary in the actual circuit. The measured self-resonant frequency of a sample transformer was lower than 1MHz.

We must guarantee that the actual circuit's demagnetizing self-resonant frequency is higher than  $f_{SW}/(1 - D_{MAX})$ . We therefore gap the core, both to reduce the transformer's measured self-resonant frequency and to reduce the variation in magnetizing inductance. Using a gapped core with  $A_1$  tolerance of 10% yields an inductance of  $144\mu H$ .

The self-resonant frequency measured for the new transformer sample is 4MHz; the transformer capacitance calculated from the expression for self-resonant frequency is 11pF. Based on the available reset time, the maximum allowable primary capacitance is 176pF. That latter value allows a maximum of 165pF for the sum of switch capacitance and reflected diode capacitance,  $C_R$ . Because MOSFET capacitance is not easily determined, we must build the circuit and adjust the value of added capacitance across the synchronous MOSFET,  $Q_R$ , to get the appropriate reset time. In the actual power supply, the added capacitance across MOSFET  $Q_R$  is 100pF.

## Output Inductor and Capacitor

The output inductor and capacitor are chosen to optimize efficiency and ensure compliance with the output-ripple specification. Thus, the inductor value is  $47\mu\text{H}$ , and  $C_O$  is formed by connecting three ceramic capacitors in parallel, each rated  $4.7\mu\text{F}$  and  $25\text{V}$ .

## Primary MOSFET

For the primary MOSFET,  $Q_1$  (voltage rating of  $250\text{V}$ ), we choose an FQD4N25 from Fairchild for its low inherent capacitance and low on-resistance. This MOSFET also minimizes the gate-drive loss, conduction loss, and switching loss.

## Synchronous-Rectifier MOSFETs

Peak stress on the synchronous rectifier,  $Q_R$ , is:

$$V_{QR} \geq \frac{\pi \times D_{\text{max}} \times V_{\text{INMIN}}}{2n_a \times (1 - D_{\text{MAX}})} \quad (\text{Eq. 10})$$

where  $n_a$  is the power transformer's actual primary-to-secondary turns ratio. In this case,  $n_a$  is 1.25 and the calculated value of  $V_{QR}$  is  $122\text{V}$ . We therefore choose a  $150\text{V}$  MOSFET for  $Q_R$ . The peak voltage stress on the freewheeling MOSFET,  $Q_F$ , is:

$$V_{QF} \geq \frac{V_{\text{INMAX}}}{n_a} \quad (\text{Eq. 11})$$

where  $n_a$  is 1.25 and  $V_{\text{INMAX}}$  is  $56\text{V}$ . The calculated value is  $44.8\text{V}$ , so for  $Q_F$  we choose a MOSFET rated at  $60\text{V}$ . (The control circuit and synchronous MOSFET drives are shown in the schematic, but not discussed further.)

## Experimental Results

Figures 4, 5, and 6 show voltage waveforms on the primary MOSFET of Figure 3 at different input voltages and various output voltages, and with an output load of  $400\text{mA}$ . The drain-voltage waveforms clearly show that the resonant-reset voltage does not vary with line voltage, but is proportional to the output voltage. Peak voltage on the primary MOSFET is equal to the input voltage plus the resonant-reset voltage.



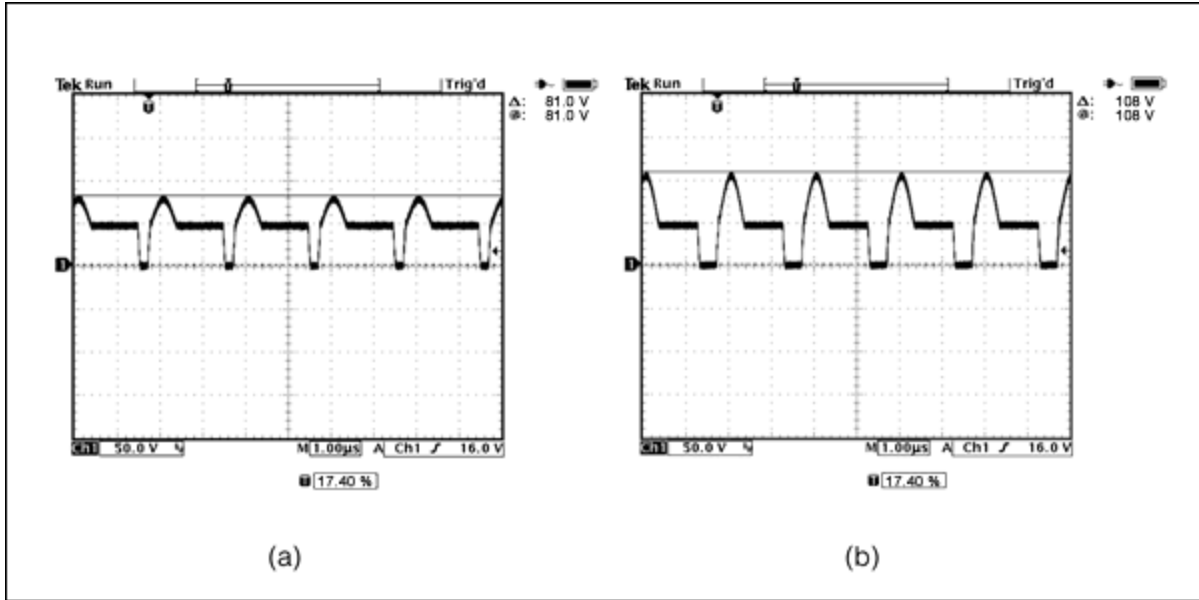


Figure 4. From Figure 3,  $V_{DS}$  on Q14 at an input of 48V<sub>DC</sub>, with output voltage at 4V (a) and 8V (b).

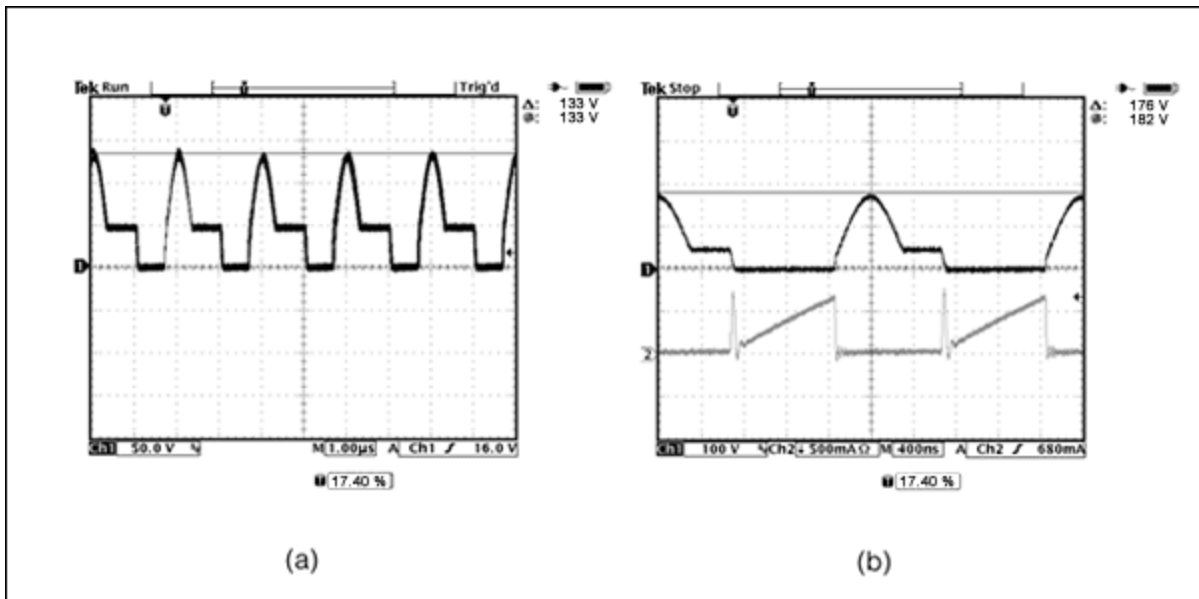


Figure 5. From Figure 3,  $V_{DS}$  on Q14 at an input of 48V<sub>DC</sub>, with output voltage at 12V (a) and 18V (b).

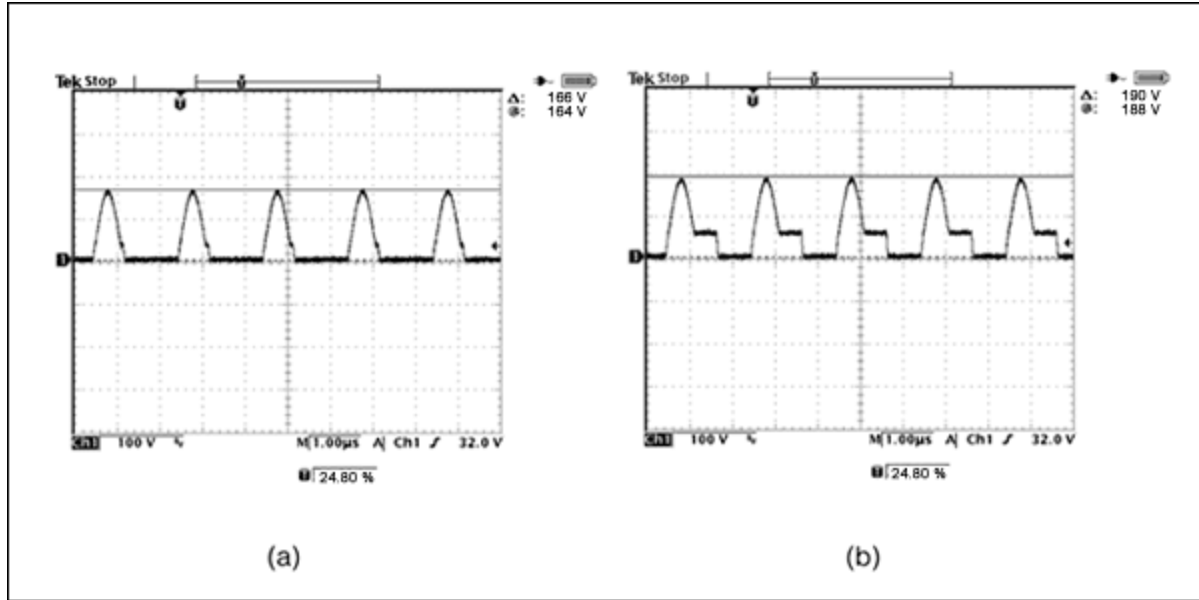


Figure 6. From Figure 3, output voltage at 18V, with  $V_{DS}$  on Q14 at an input of  $36V_{DC}$  (a) and  $56V_{DC}$  (b).

## Conclusion

Resonant-reset forward converters are quite suitable for power supplies operating from wide-range DC-voltage inputs. They are also suitable for applications requiring a wide range of adjustable output voltage. In designing resonant-reset forward converters, you should minimize the stress of transient voltages on the devices; using synchronous rectification reduces transient-voltage stress on the power semiconductors. For optimum performance you should also choose an appropriate controller.

### Related Parts

<a href="#">MAX5048</a>	7.6A, 12ns, SOT23/TDFN MOSFET Driver	<a href="#">Free Samples</a>
<a href="#">MAX8515</a>	Wide-Input 0.6V Shunt Regulators for Isolated DC-DC Converters	<a href="#">Free Samples</a>
<a href="#">MAX9010</a>	SC70, 5ns, Low-Power, Single-Supply, Precision TTL Comparators	<a href="#">Free Samples</a>

### More Information

For Technical Support: <http://www.maximintegrated.com/support>

For Samples: <http://www.maximintegrated.com/samples>

Other Questions and Comments: <http://www.maximintegrated.com/contact>

Application Note 3983: <http://www.maximintegrated.com/an3983>

APPLICATION NOTE 3983, AN3983, AN 3983, APP3983, Appnote3983, Appnote 3983

Copyright © by Maxim Integrated Products

Additional Legal Notices: <http://www.maximintegrated.com/legal>